

HSM2836C

Silicon Epitaxial Planar Diode for High Speed Switching

REJ03G0554-0400

(Previous: ADE-208-030C)

Rev.4.00 Mar 10, 2005

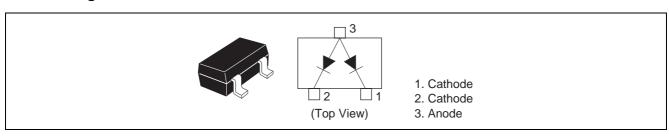
Features

- Fast recovery time.
- MPAK package is suitable for high density surface mounting and high speed assembly.

Ordering Information

Type No.	Laser Mark	Package Name	Package Code (Previous Code)
HSM2836C	A4	MPAK	PLSP0003ZC-A (MPAK)

Pin Arrangement



Absolute Maximum Ratings *1

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Peak reverse voltage	V_{RM}	85	V
Reverse voltage	V _R	80	V
Peak forward current	I _{FM}	300	mA
Non-Repetitive peak forward surge current	I _{FSM} * ²	4	Α
Average rectified current	Io	100	mA
Junction temperature	Tj	125	°C
Storage temperature	Tstg	−55 to +125	°C

Notes: 1. Per one device.

2. Within 1 μs forward surge current.

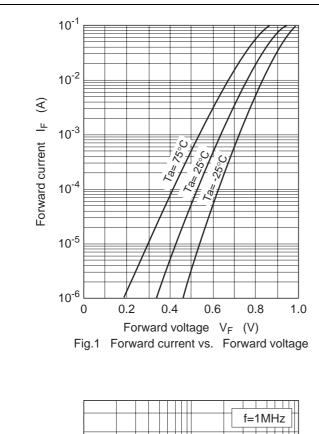
Electrical Characteristics *1

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	V_{F1}	_	0.72	1.0	V	I _F = 10 mA
	V _{F2}	_	0.83	1.0		I _F = 50 mA
	V _{F3}	_	0.90	1.2		I _F = 100 mA
Reverse current	I _R	_	_	0.1	μΑ	V _R = 80 V
Capacitance	С	_	2.5	4.0	pF	V _R = 0 V, f = 1 MHz
Reverse recovery time	t _{rr}	_	_	20	ns	$I_F = 10 \text{ mA}, V_R = 6 \text{ V}, R_L = 50 \Omega$

Note: 1. Per one device.

Main Characteristic



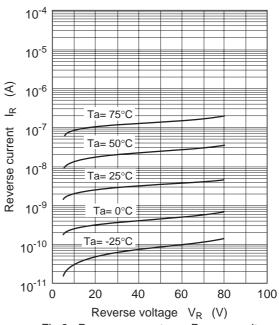


Fig.2 Reverse current vs. Reverse voltage

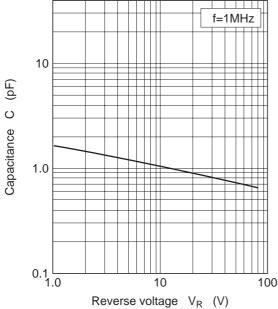
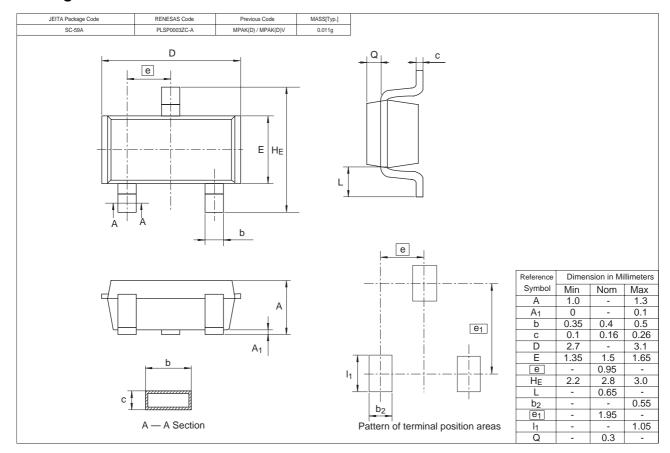


Fig.3 Capacitance vs. Reverse voltage

Package Dimensions



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